# Low Voltage Automotive Fast 32K x 8 SRAM

### **Features**

## ☐ 32768 x 8 bit static CMOS RAM ☐ 35 and 55 ns Access Time Common data inputs and data outputs Three-state outputs ☐ Typ. operating supply current 35 ns: 45 mA 55 ns: 30 mA ☐ Standby current < 40 µA at 125 °C ☐ TTL/CMOS-compatible ☐ Power supply voltage 2.5 - 3.6 V Operating temperature range -40 °C to 85 °C -40 °C to 125 °C ☐ QS 9000 Quality Standard ☐ ESD protection > 2000 V (MIL STD 883C M3015.7)

☐ Latch-up immunity >100 mA

☐ Package: SOP28 (300/330 mil)

## **Description**

The UL62H256A is a static RAM manufactured using a CMOS process technology with the following operating modes:

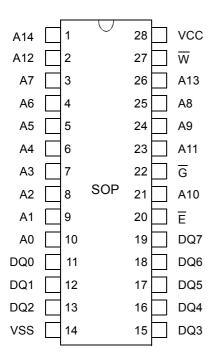
- Read Standby
- Write Data Retention The memory array is based on a 6-Transistor cell.

The circuit is activated by the falling edge of  $\overline{E}$ . The address and control inputs open simultaneously. According to the information of  $\overline{W}$  and  $\overline{G}$ , the data inputs, or outputs, are active. In a Read cycle, the data outputs are activated by the falling edge of  $\overline{G}$ , afterwards the data word will be available at the outputs DQ0-DQ7. After the address change, the data outputs

go High-Z until the new information is available. The data outputs have no preferred state. The Read cycle is finished by the falling edge of  $\overline{\mathbf{W}}$ , or by the rising edge of  $\overline{\mathbf{E}}$ , respectively.

Data retention is guaranteed down to 2 V. With the exception of  $\overline{E}$ , all inputs consist of NOR gates, so that no pull-up/pull-down resistors are required.

### **Pin Configuration**



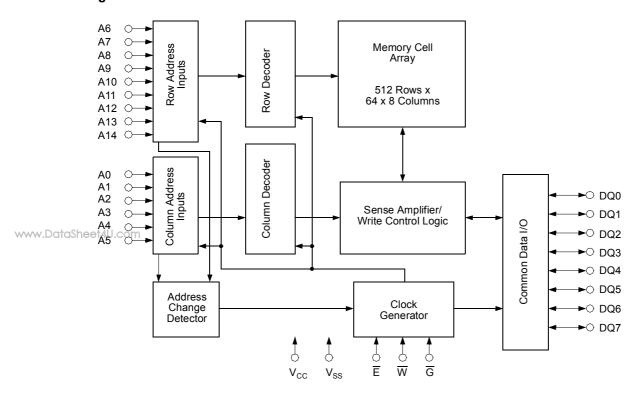
### **Pin Description**

Signal Name	Signal Description
A0 - A14	Address Inputs
DQ0 - DQ7	Data In/Out
Ē	Chip Enable
G	Output Enable
W	Write Enable
vcc	Power Supply Voltage
VSS	Ground

Top View

# **UL62H256A**

## **Block Diagram**



## **Truth Table**

Operating Mode	Ē	w	G	DQ0 - DQ7
Standby/not selected	Н	*	*	High-Z
Internal Read	L	Н	Н	High-Z
Read	L	Н	L	Data Outputs Low-Z
Write	L	L	*	Data Inputs High-Z

<sup>\*</sup> H or L



### **Characteristics**

All voltages are referenced to  $V_{\rm SS}$  = 0 V (ground).

All characteristics are valid in the power supply voltage range and in the operating temperature range specified. Dynamic measurements are based on a rise and fall time of  $\leq$  5 ns, measured between 10 % and 90 % of V<sub>I</sub>, as well as input levels of V<sub>IL</sub> = 0.2 V and V<sub>IH</sub> = 2.8 V. The timing reference level of all input and output signals is 1.5 V, with the exception of the t<sub>dis</sub>-times and t<sub>en</sub>-times, in which cases transition is measured  $\pm$ 200 mV from steady-state voltage.

	Absolute Maximum Ratings <sup>a</sup>		Symbol	Min.	Max.	Unit
	Power Supply Voltage		V <sub>CC</sub>	-0.3	4.6	V
	Input Voltage		V <sub>I</sub>	-0.5	V <sub>CC</sub> + 0.5 <sup>b</sup>	V
	Output Voltage		V <sub>O</sub>	-0.5	V <sub>CC</sub> + 0.5 <sup>b</sup>	V
	Power Dissipation		P <sub>D</sub>	-	1	W
WWV	Operating Temperature	K-Type A-Type	Та	-40 -40	85 125	°C
	Storage Temperature		T <sub>stg</sub>	-65	150	°C
	Output Short-Circuit Currer at V <sub>CC</sub> = 3.3 V and V <sub>O</sub> = 0 V	I <sub>os</sub>		100	mA	

<sup>&</sup>lt;sup>a</sup> Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at condition above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability

 $<sup>^{\</sup>rm c}$  Not more than  $\overset{\circ}{1}$  output should be shorted at the same time. Duration of the short circuit should not exceed 30 s.

Recommended Operating Conditions	Symbol	Conditions	Min.	Max.	Unit
Power Supply Voltage	V <sub>CC</sub>		2.5	3.6	V
Input Low Voltage d	V <sub>IL</sub>		-0.3	0.5	V
Input High Voltage	V <sub>IH</sub>		2.0	V <sub>CC</sub> + 0.3	V

d -2 V at Pulse Width 30 ns

b Maximum voltage is 4.6 V

# **UL62H256A**

Electrical Characteristics	Symbol	Co	nditions	Min.	Max.	Unit
Supply Current - Operating Mode	I <sub>CC(OP)</sub>	V <sub>CC</sub> V <sub>IL</sub> V <sub>IH</sub> t <sub>cW</sub>	= 3.6 V = 0.5 V = 2.0 V = 35 ns = 55 ns		90 70	mA mA
Supply Current - Standby Mode (CMOS level)	I <sub>CC(SB)</sub>	V <sub>CC</sub> V <sub>E</sub> K-Type A-Type	= 3.6 V = V <sub>CC</sub> - 0.2 V		10 40	μΑ μΑ
Supply Current - Standby Mode	I <sub>CC(SB)1</sub>	V <sub>CC</sub> V <sub>E</sub> K-Type A-Type	= 3.6 V = 2.0 V		10 20	mA mA
Output High Voltage	V <sub>OH</sub>	V <sub>CC</sub>	= 2.5 V	2.2		V
Output Low Voltage	V <sub>OL</sub>	I <sub>OH</sub> V <sub>CC</sub> I <sub>OL</sub>	= -1.0 mA = 2.5 V = 2.1 mA		0.4	V
Input High Leakage Current	I <sub>IH</sub>	V <sub>CC</sub>	= 3.6 V		2	μΑ
Input Low Leakage Current	I <sub>IL</sub>	V <sub>IH</sub> V <sub>CC</sub> V <sub>IL</sub>	= 3.6 V = 3.6 V = 0 V	-2		μΑ
Output High Current	Іон	V <sub>CC</sub>	= 2.5 V = 2.2 V		-1.0	mA
Output Low Current	I <sub>OL</sub>	V <sub>OH</sub> V <sub>CC</sub> V <sub>OL</sub>	= 2.2 V = 2.5 V = 0.4 V	2.1		mA
Output Leakage Current		N/	- 201/			4
High at Three-State Outputs	I <sub>OHZ</sub>	V <sub>CC</sub> V <sub>OH</sub>	= 3.6 V = 3.6 V		2	μA
Low at Three-State Outputs	I <sub>OLZ</sub>	V <sub>CC</sub>	= 3.6 V = 0 V	-2		μΑ

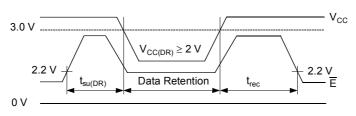


Switching Characteristics	Syn	nbol	35		55		Unit
Read Cycle	Alt.	IEC	Min.	Max.	Min.	Max.	Onit
Read Cycle Time	t <sub>RC</sub>	t <sub>cR</sub>	35		55		ns
Address Access Time to Data Valid	t <sub>AA</sub>	t <sub>a(A)</sub>		35		55	ns
Chip Enable Access Time to Data Valid	t <sub>ACE</sub>	t <sub>a(E)</sub>		35		55	ns
G LOW to Data Valid	t <sub>OE</sub>	t <sub>a(G)</sub>		15		25	ns
E HIGH to Output in High-Z	t <sub>HZCE</sub>	t <sub>dis(E)</sub>		12		15	ns
G HIGH to Output in High-Z	t <sub>HZOE</sub>	t <sub>dis(G)</sub>		12		15	ns
E LOW to Output in Low-Z	t <sub>LZCE</sub>	t <sub>en(E)</sub>	3		3		ns
G LOW to Output in Low-Z	t <sub>LZOE</sub>	t <sub>en(G)</sub>	0		0		ns
Output Hold Time from Address Change	t <sub>OH</sub>	t <sub>v(A)</sub>	3		3		ns
E LOW to Power-Up Time	t <sub>PU</sub>		0		0		ns
E HIGH to Power-Down Time	t <sub>PD</sub>			35		55	ns

Switching Characteristics	Syn	nbol	35		55		Unit
Write Cycle	Alt.	IEC	Min.	Max.	Min.	Max.	Unit
Write Cycle Time	t <sub>WC</sub>	t <sub>cW</sub>	35		55		ns
Write Pulse Width	t <sub>WP</sub>	t <sub>w(W)</sub>	20		35		ns
Write Setup Time	t <sub>WP</sub>	t <sub>su(W)</sub>	20		35		ns
Address Setup Time	t <sub>AS</sub>	t <sub>su(A)</sub>	0		0		ns
Address Valid to End of Write	t <sub>AW</sub>	t <sub>su(A-WH)</sub>	25		40		ns
Chip Enable Setup Time	t <sub>CW</sub>	t <sub>su(E)</sub>	25		40		ns
Pulse Width Chip Enable to End of Write	t <sub>CW</sub>	t <sub>w(E)</sub>	25		40		ns
Data Setup Time	t <sub>DS</sub>	t <sub>su(D)</sub>	15		25		ns
Data Hold Time	t <sub>DH</sub>	t <sub>h(D)</sub>	0		0		ns
Address Hold from End of Write	t <sub>AH</sub>	t <sub>h(A)</sub>	0		0		ns
W LOW to Output in High-Z	t <sub>HZWE</sub>	t <sub>dis(W)</sub>		15		20	ns
G HIGH to Output in High-Z	t <sub>HZOE</sub>	t <sub>dis(G)</sub>		12		15	ns
W HIGH to Output in Low-Z	t <sub>LZWE</sub>	t <sub>en(W)</sub>	0		0		ns
G LOW to Output in Low-Z	t <sub>LZOE</sub>	t <sub>en(G)</sub>	0		0		ns

### **Data Retention Mode**

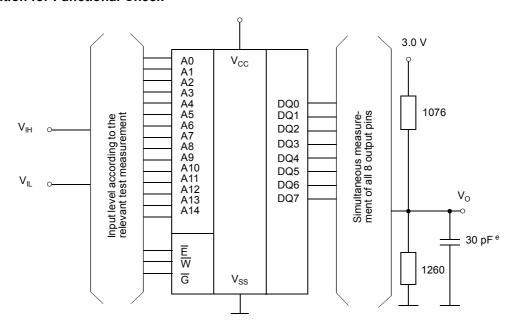
# E - controlled



 $V_{CC(DR)}$  - 0.2  $V \le V_{\overline{E}(DR)} \le V_{CC(DR)}$  + 0.3 V

Data Retention	Symbol		Conditions	Min	T	Max	11
Characteristics	Alt.	IEC	Conditions	Min.	Тур.	Max.	Unit
Data Retention Supply Voltage		V <sub>CC(DR)</sub>		2			V
Data Retention Supply Current		I <sub>CC(DR)</sub>	$V_{CC(DR)} = 2V$ $V_{\overline{E}} = V_{CC(DR)} - 0.2 V$ K-Type A-Type			5 20	μΑ μΑ
Data Retention Setup Time	t <sub>CDR</sub>	t <sub>su(DR)</sub>	See Data Retention	0			ns
Operating Recovery Time	t <sub>R</sub>	t <sub>rec</sub>	Waveforms (above)	t <sub>cR</sub>			ns

## **Test Configuration for Functional Check**



 $<sup>^{\</sup>rm e}$  In measurement of  $t_{\rm dis(E)}$ ,  $t_{\rm dis(W)}$ ,  $t_{\rm en(E)}$ ,  $t_{\rm en(W)}$ ,  $t_{\rm en(G)}$  the capacitance is 5 pF.

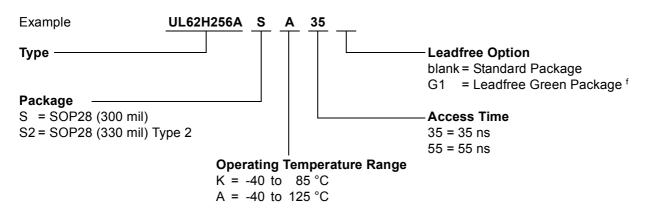


Capacitance	Conditions	Symbol	Min.	Max.	Unit
Input Capacitance	$V_{CC} = 3.3 V$ $V_{I} = V_{SS}$	C <sub>I</sub>		7	pF
Output Capacitance		C <sub>o</sub>		7	pF

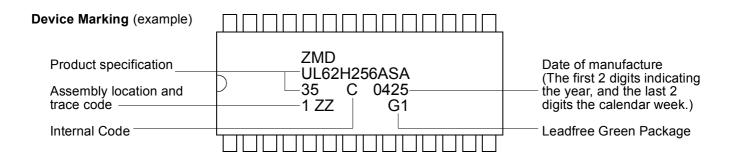
All pins not under test must be connected with ground by capacitors.

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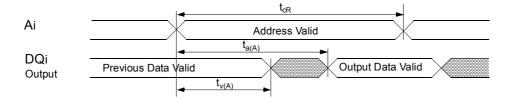
## **Ordering Code**



f on special request

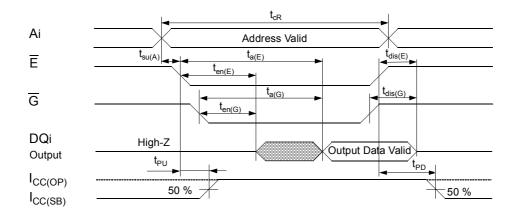


Read Cycle 1:  $A_i$ -controlled (during Read Cycle :  $\overline{E} = \overline{G} = V_{IL}$ ,  $\overline{W} = V_{IH}$ )

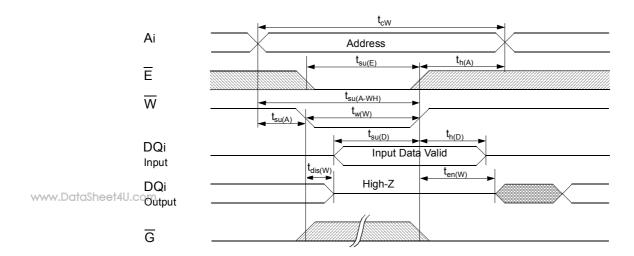


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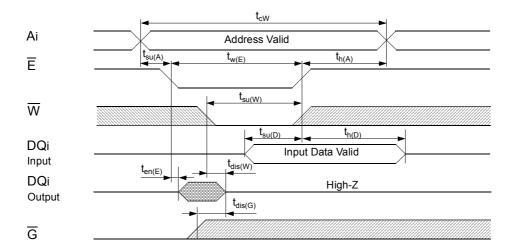
# Read Cycle 2: $\overline{G}$ -, $\overline{E}$ -controlled (during Read Cycle: $\overline{W} = V_{IH}$ )



# Write Cycle1: W-controlled



# Write Cycle 2: E-controlled





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